NSN 5961-00-189-0550

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View Online at https://aerobasegroup.com/nsn/5961-00-189-0550 **Inclosure Material:** Metal **Overall Length:** 0.375 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to emitter reverse voltage and 100.0 collector to base voltage, dc and 90.0 collector to emitter voltage/static/base open and 4.0 emitter to base voltage, instantaneous **Current Rating Per Characteristic:** Between 7.50 amperes source cutoff current and 30.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 200.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0